

Supporting Information

Thermal Diffusivity of Hexagonal Boron Nitride Composites Based on Cross-Linked Liquid Crystalline Polyimides

Yu Shoji,[†] Tomoya Higashihara,^{†,‡} Masatoshi Tokita,[†] Junko Morikawa,[†] Junji Watanabe,[†] and Mitsuru Ueda^{†*}

[†] *Department of Organic and Polymeric Materials, Graduate School of Science and Engineering, Tokyo Institute of Technology, 2-12-1-H-120, O-okayama, Meguro-Ku, Tokyo 152-8550, Japan*

[‡] *PRESTO, Japan Science and Technology Agency (JST), 4-1-8, Honcho, Kawaguchi, Saitama 332-0012, Japan*

E-mail addresses: ueda.m.ad@m.titech.ac.jp

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Experimental data for non cross-linked **P1**. IR (Si wafer), ν (cm^{-1}): 2958 (Alkyl C–H), 1770 (C=O), 1712 (C=O), 1385 (C–N), 1257 (Si–C). ^1H NMR (300 MHz, CDCl_3 , δ , ppm, 25 °C): 8.19 (s, ArH, 2H), 8.05 (s, ArH, 4H), 7.33 (d, $J=8.7$ Hz, ArH, 4H), 7.01 (d, $J=8.7$ Hz, ArH, 4H), 4.00 (t, $J=6.0$, $-\text{CH}_2-$, 4H), 3.35 (s, $-\text{C}\equiv\text{CH}$), 1.89–1.77 (m, $-\text{CH}_2-$, 4H), 1.59–1.48 (m, $-\text{CH}_2-$, 4H), 0.65–0.59 (m, $-\text{CH}_2-$, 4H), 0.11 (s, Si–CH₃, 12H), 0.07 (s, Si–CH₃, 12H). ^{13}C NMR (75 MHz, CDCl_3 , δ , ppm, 25 °C): 167.2, 159.2, 145.5, 133.4, 133.2, 131.8, 128.0, 124.7, 124.0, 122.6, 115.2, 81.9, 68.5, 68.0, 32.8, 19.8, 18.0, 1.40, 0.368. Anal. Calcd. For $-(\text{C}_{44}\text{H}_{54}\text{N}_2)_n-$: C, 60.94; H, 6.28; N, 3.23. Found: C, 60.50 ; H, 6.18 ; N, 3.11.

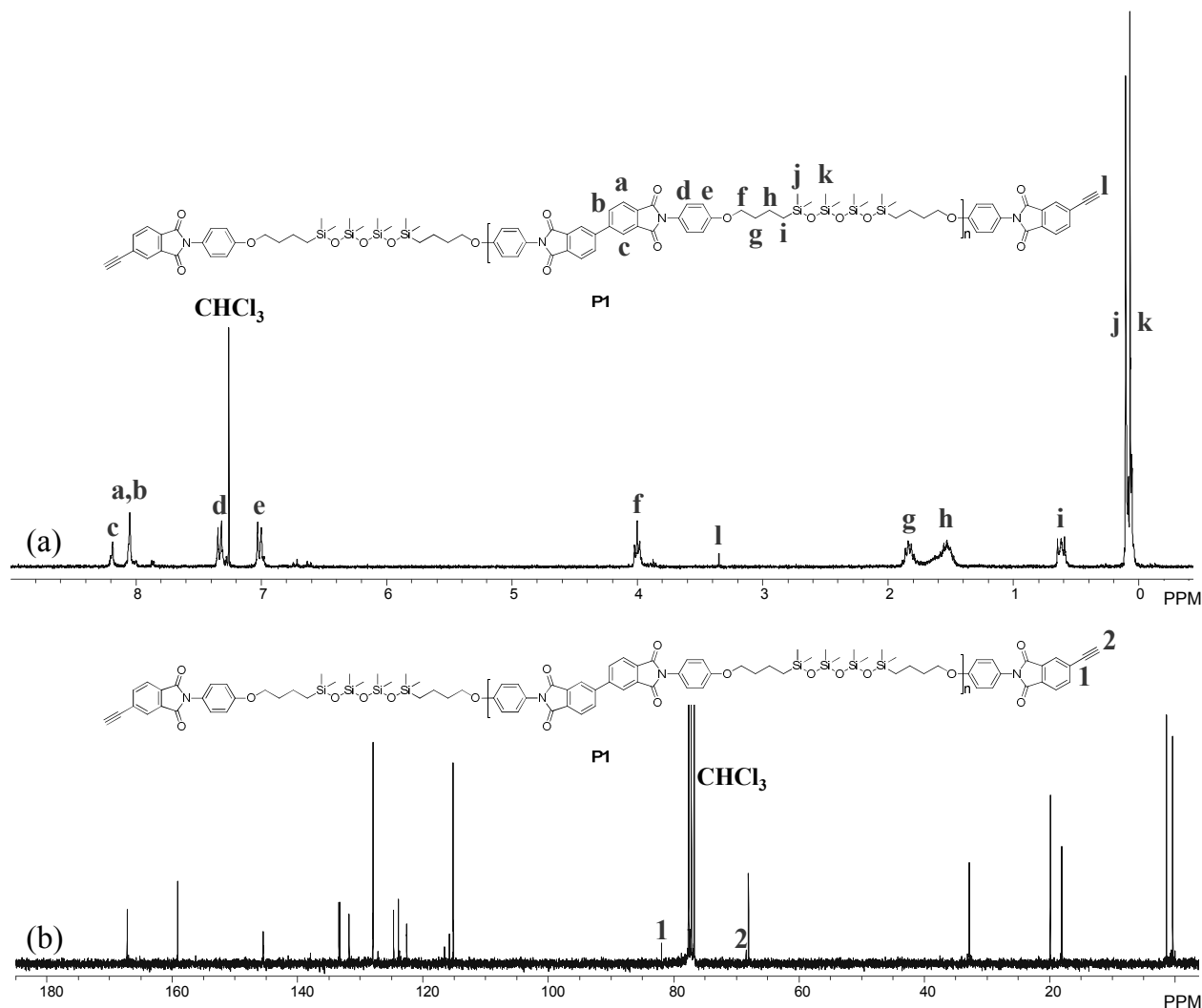


Figure S1. (a) ^1H and (b) ^{13}C NMR spectra of non cross-linked **P1** in CDCl_3 .

Experimental data for **P2**. IR (Si wafer), ν (cm^{-1}): 2958 (Alkyl C–H), 1774 (C=O), 1716 (C=O), 1381 (C–N), 1254 (Si–C). ^1H NMR (300 MHz, CDCl_3 , δ , ppm, 25 $^\circ\text{C}$): 8.23 (s, ArH, 2H), 8.08 (s, ArH, 4H), 7.12 (d, $J=8.4$ Hz, ArH, 4H), 6.89 (s, ArH, 2H), 6.86 (d, $J=8.4$ Hz, ArH, 2H), 3.99 (t, $J=6.3$ Hz, $-\text{CH}_2-$, 4H), 2.19 (s, $-\text{CH}_3$, 6H), 1.88–1.79 (m, $-\text{CH}_2-$, 4H), 1.58–1.48 (m, $-\text{CH}_2-$, 4H), 0.65–0.60 (m, $-\text{CH}_2-$, 4H), 0.11 (s, Si– CH_3 , 12H), 0.08 (s, Si– CH_3 , 12H). ^{13}C NMR (75 MHz, CDCl_3 , δ , ppm, 25 $^\circ\text{C}$): 167.3, 160.0, 145.5, 137.9, 133.4, 133.3, 132.0, 129.7, 124.7, 122.8, 122.7, 117.1, 112.9, 67.9, 32.9, 19.9, 18.4, 18.1, 1.41, 0.379. Anal. Calcd. For $-(\text{C}_{46}\text{H}_{58}\text{N}_2)_n-$: C, 61.71; H, 6.53; N, 3.13. Found: C, 61.00; H, 6.25; N, 3.12.

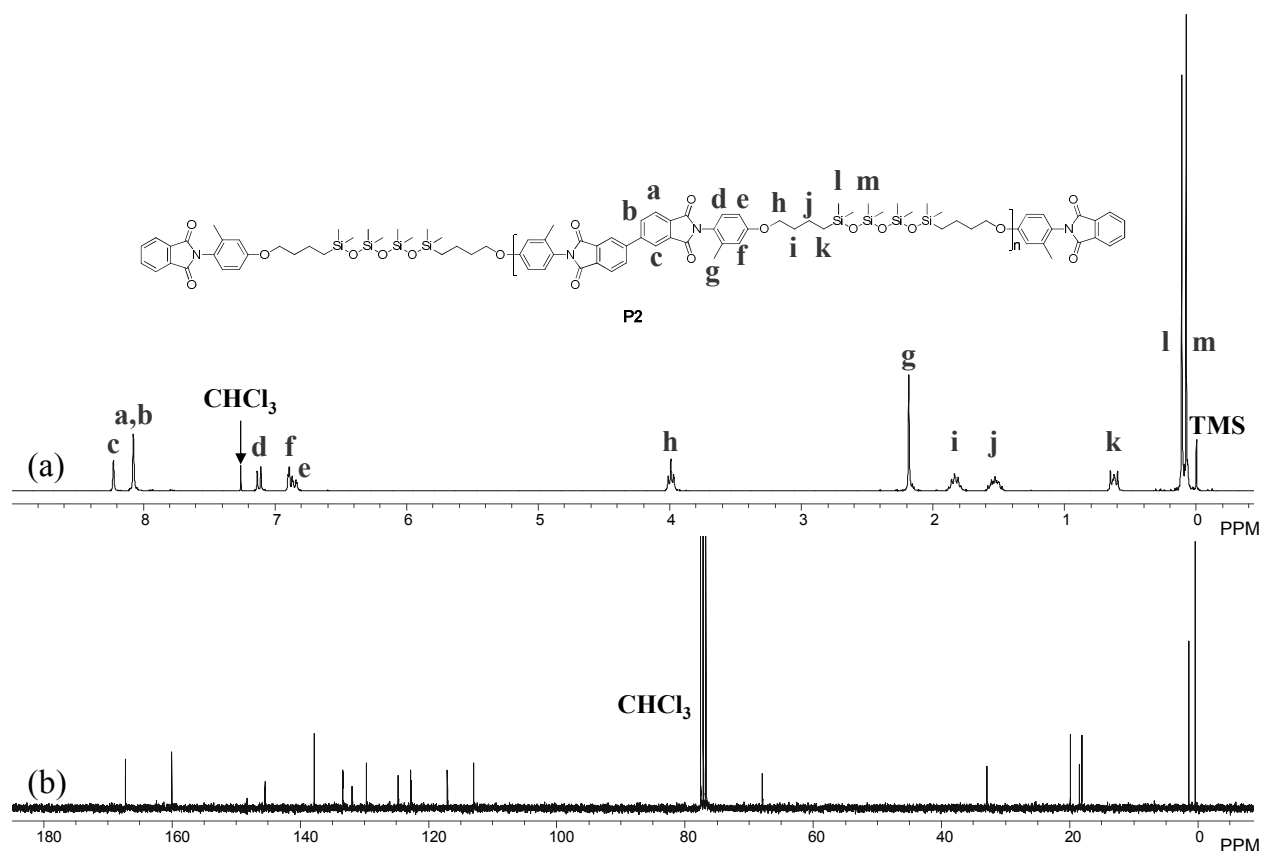


Figure S2. (a) ^1H and (b) ^{13}C NMR spectra of **P2** in CDCl_3 .

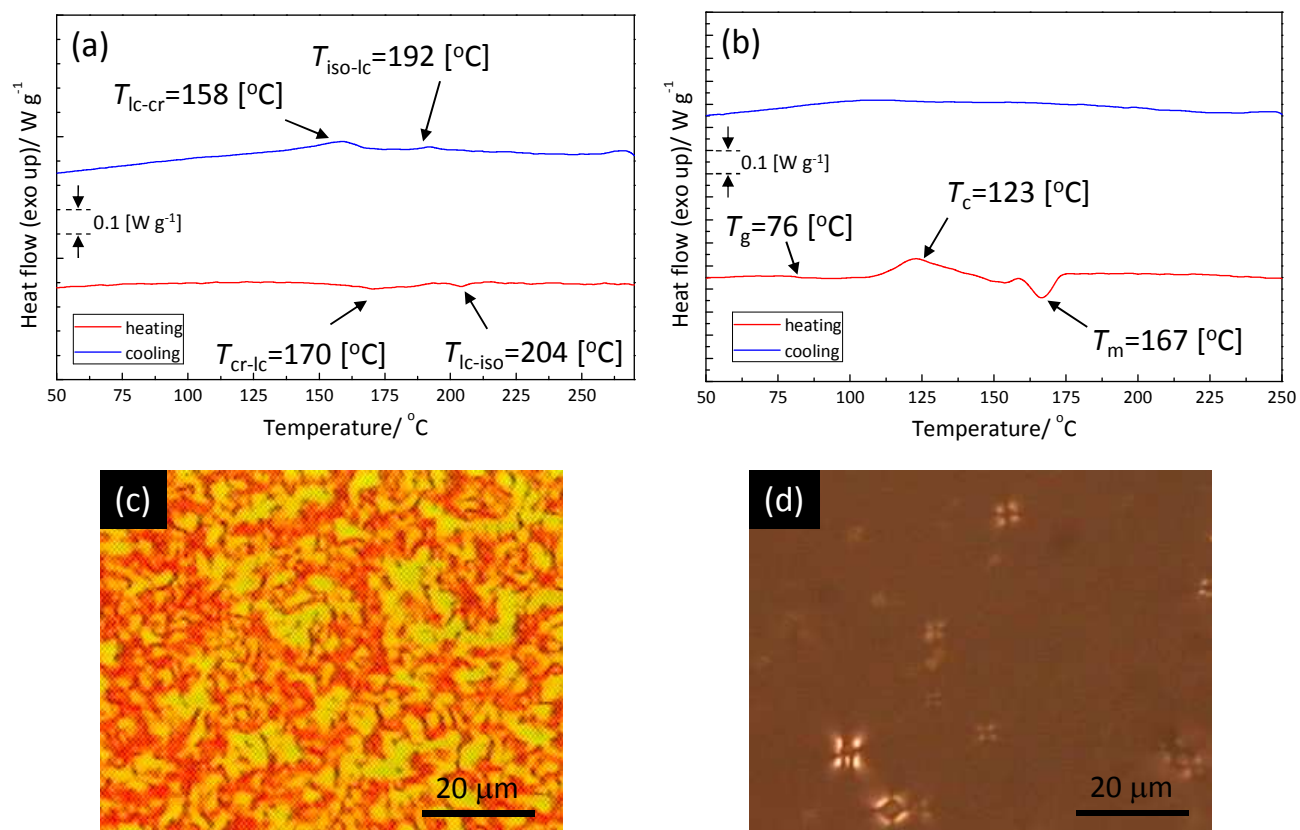


Figure S3. DSC traces for polyimide (a) **P1** and (b) **P2**. POM images of (c) **P1** and (d) **P2** at room temperature.

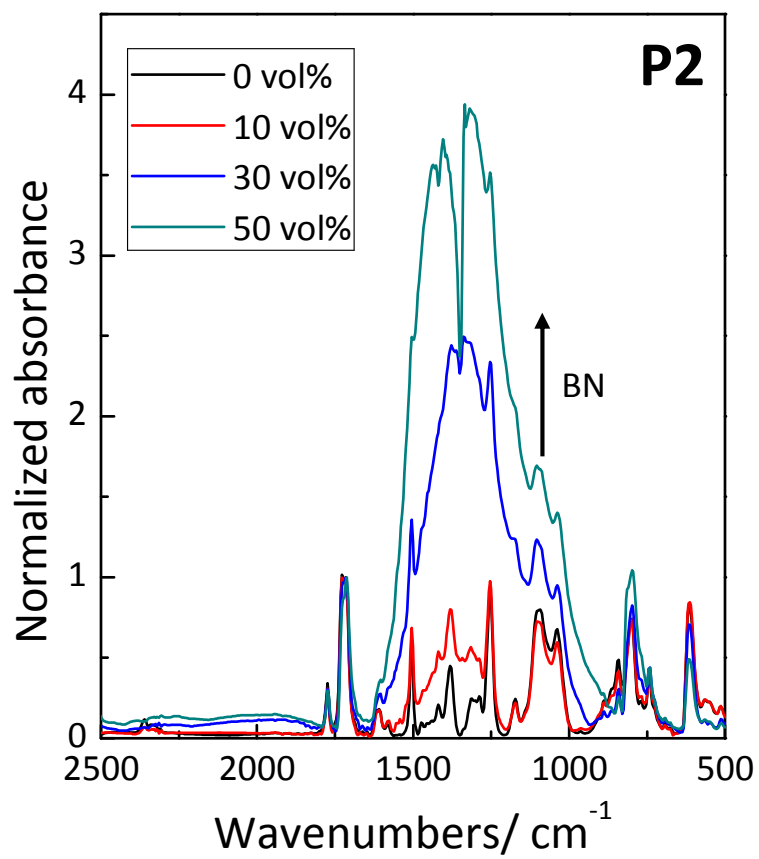


Figure S4. FT-IR spectra of h-BN composites of **P2**.

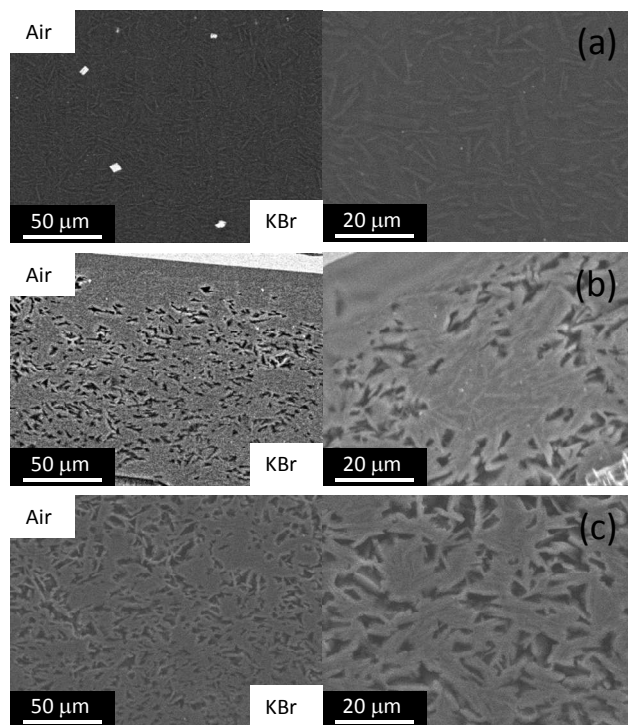


Figure S5. SEM images of cross-sectional area for the (a) 20 vol% and (b) 50 vol% h-BN composite films of **P1**, and the (c) 50 vol% h-BN composite film of **P2** (15.0 kV, $\times 600$ (left) and $\times 1,500$ (right)). Air interface side (upper) and KBr substrate side (bottom) in each figure.

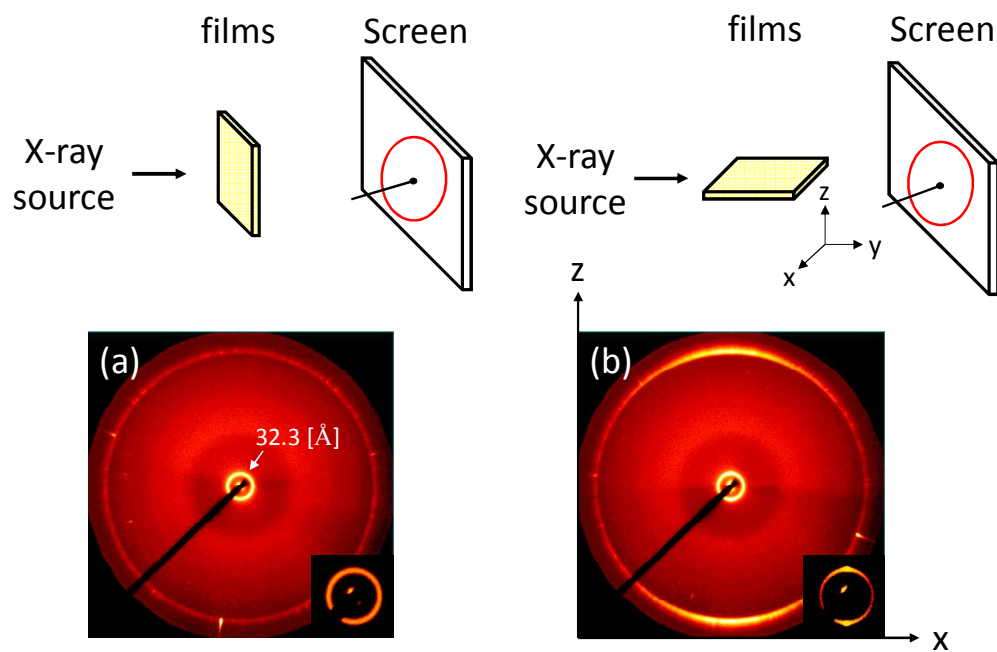


Figure S6. WAXD patterns (a) perpendicular and (b) parallel to the film surface for the 20 vol% h-BN composite film of **P1**.

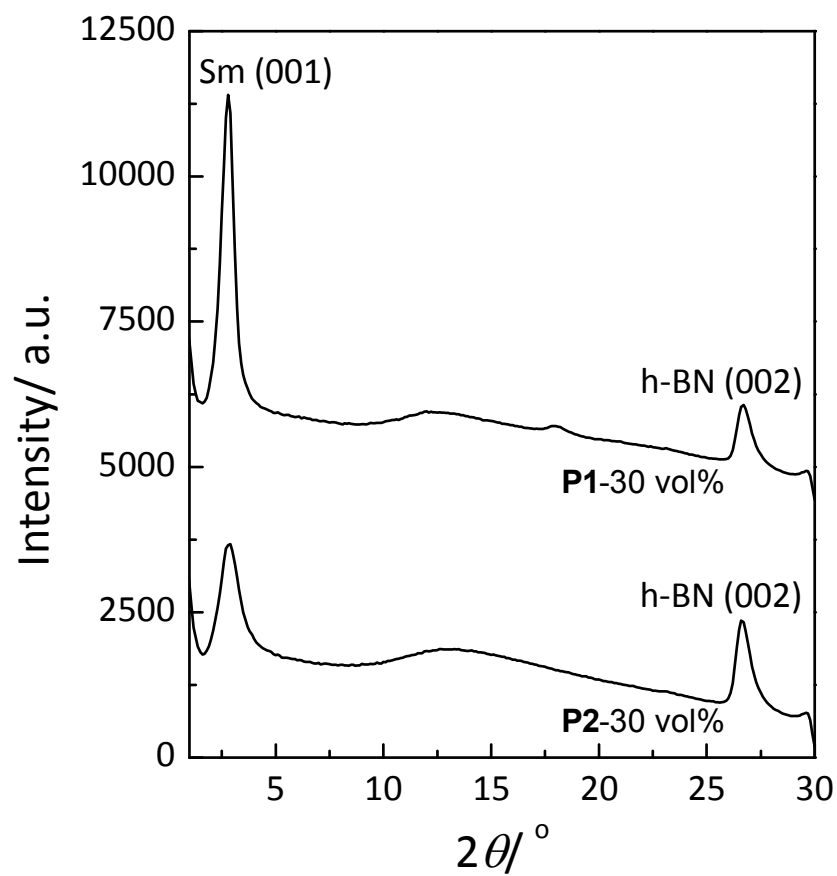


Figure S7. The intensity profiles of WAXD patterns by the beam irradiation perpendicular to the film surface for the 30 vol% h-BN composite films of **P1** (upper) and **P2** (bottom) against 2θ .

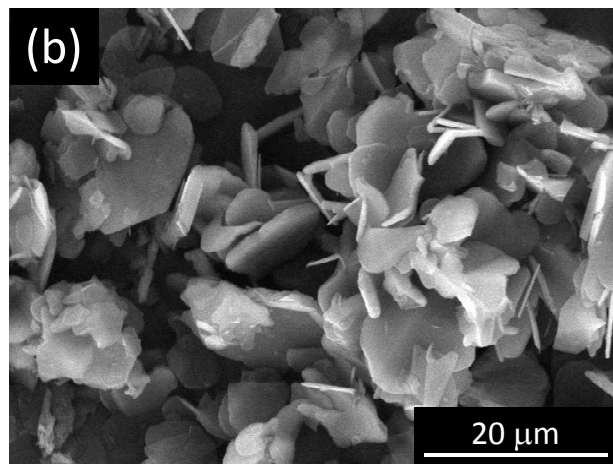
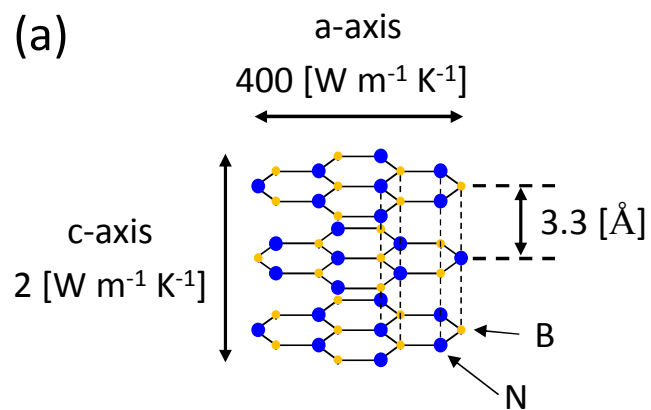


Figure S8. (a) The schematic illustration of the h-BN lattice structure and (b) the SEM image of the h-BN flakes.

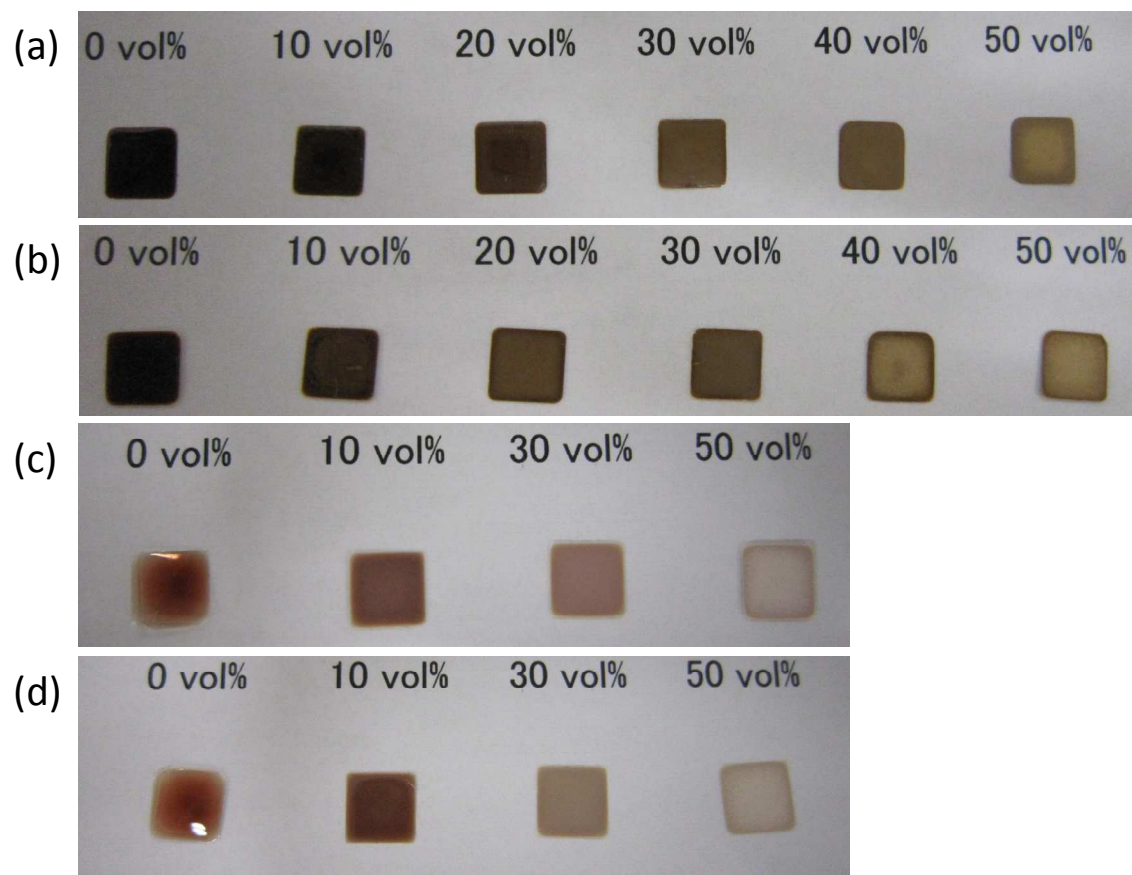


Figure S9. The photos of the obtained h-BN composite films: (a) air surface side of composite films of **P1**, (b) KBr substrate side of composite films of **P1**, (c) air surface side of composite films of **P2**, (d) KBr substrate side of composite films of **P2**.